## NSN 5961-01-513-5503

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-513-5503 **Inclosure Material:** Glass **Overall Length:** 0.235 inches **Overall Width:** 0.135 inches **Features Provided:** Hermetically sealed case and quality assurance level tx Voltage Rating In Volts Per Characteristic: 40.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 1.00 amperes forward current, average absolute **Special Features:** Op temp m55 to p125 degrees c; low fwd voltage drop; low profile surface mt; schottky **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**